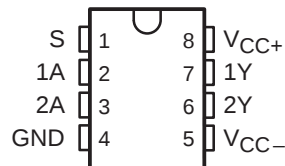


- Meets or Exceeds the Requirement of TIA/EIA-232-F and ITU Recommendation V.28
- Withstands Sustained Output Short Circuit to Any Low-Impedance Voltage Between –25 V and 25 V
- 2-μs Maximum Transition Time Through the 3-V to –3-V Transition Region Under Full 2500-pF Load
- Inputs Compatible With Most TTL Families
- Common Strobe Input
- Inverting Output
- Slew Rate Can Be Controlled With an External Capacitor at the Output
- Standard Supply Voltages . . . ± 12 V

D OR P PACKAGE
(TOP VIEW)

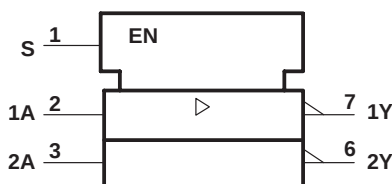


description

The SN75150 is a monolithic dual line driver designed to satisfy the requirements of the standard interface between data-terminal equipment and data-communication equipment as defined by TIA/EIA-232-F. A rate of 20 kbits/s can be transmitted with a full 2500-pF load. Other applications are in data-transmission systems using relatively short single lines, in level translators, and for driving MOS devices. The logic input is compatible with most TTL families. Operation is from 12-V and –12-V power supplies.

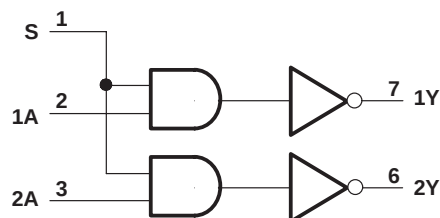
The SN75150 is characterized for operation from 0°C to 70°C.

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)

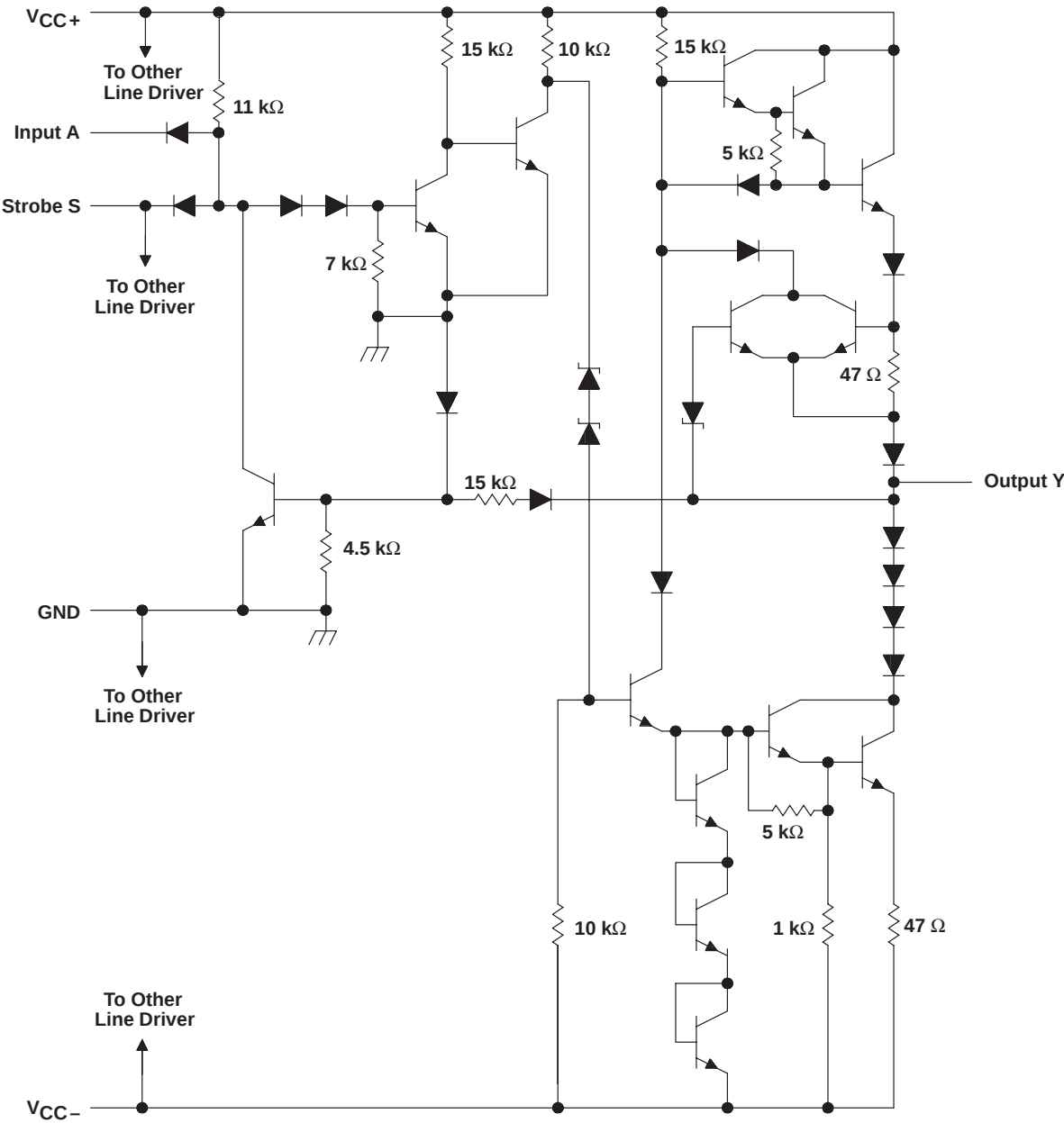


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SN75150 DUAL LINE DRIVER

SLLS081C – JANUARY 1971 – REVISED JUNE 1999

schematic (each line driver)



Resistor values shown are nominal.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage, V_{CC+} (see Note 1)	15 V
Supply voltage, V_{CC-}	–15 V
Input voltage, V_I	15 V
Applied output voltage	±25 V
Package thermal impedance, θ_{JA} (see Notes 2 and 3): D package	197°C/W
P package	104°C/W
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C
Storage temperature range, T_{stg}	–65°C to 150°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES:
1. Voltage values are with respect to network ground terminal.
 2. Maximum power dissipation is a function of $T_J(\max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(\max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can impact reliability.
 3. The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

recommended operating conditions

		MIN	NOM	MAX	UNIT
Supply voltage	V_{CC+}	10.8	12	13.2	V
	V_{CC-}	–10.8	–12	–13.2	
High-level input voltage, V_{IH}		2		5.5	V
Low-level input voltage, V_{IL}		0		0.8	V
Driver output voltage, V_O				±15	V
Operating free-air temperature, T_A		0		70	°C

SN75150

DUAL LINE DRIVER

SLLS081C – JANUARY 1971 – REVISED JUNE 1999

electrical characteristics over recommended operating free-air temperature range, $V_{CC\pm} = \pm 13.2$ V (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP [†]	MAX	UNIT
V_{OH}	High-level output voltage	$V_{CC+} = 10.8$ V, $V_{IL} = 0.8$ V, $V_{CC-} = -10.8$ V, $R_L = 3$ k Ω to 7 k Ω	5	8		V
V_{OL}	Low-level output voltage (see Note 4)	$V_{CC+} = 10.8$ V, $V_{IH} = 2$ V, $V_{CC-} = -10.8$ V, $R_L = 3$ k Ω to 7 k Ω		-8	-5	V
I_{IH}	High-level input current	$V_I = 2.4$ V		1	10	μ A
	Strobe input			2	20	
I_{IL}	Low-level input current	$V_I = 0.4$ V		-1	-1.6	mA
	Strobe input			-2	-3.2	
I_{OS}	Short-circuit output current [‡]	$V_O = 25$ V		2	8	mA
		$V_O = -25$ V		-3	-8	
		$V_O = 0$, $V_I = 3$ V	10	15	30	
		$V_O = 0$, $V_I = 0$	-10	-15	-30	
I_{CCH+}	Supply current from V_{CC+} , high-level output	$V_I = 0$, $R_L = 3$ k Ω , $T_A = 25^\circ$ C		10	22	mA
I_{CCH-}	Supply current from V_{CC-} , high-level output			-1	-10	mA
I_{CCL+}	Supply current from V_{CC+} , low-level output	$V_I = 3$ V, $R_L = 3$ k Ω , $T_A = 25^\circ$ C		8	17	mA
I_{CCL-}	Supply current from V_{CC-} , low-level output			-9	-20	mA

[†] All typical values are at $V_{CC+} = 12$ V, $V_{CC-} = -12$ V, $T_A = 25^\circ$ C.

[‡] Not more than one output should be shorted at a time.

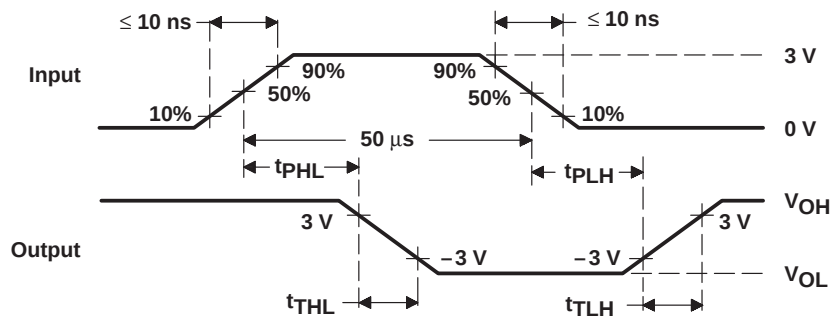
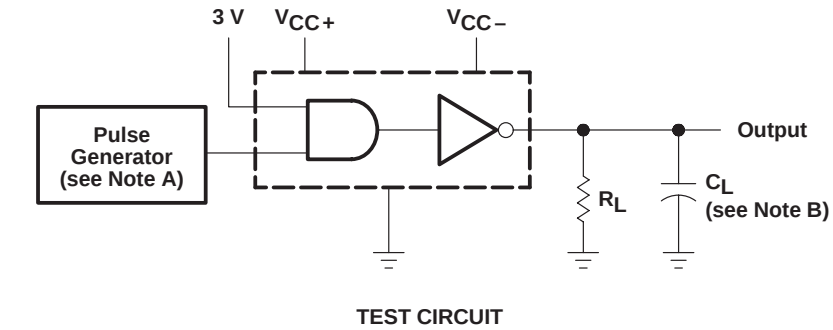
NOTE 4: The algebraic convention, in which the less positive (more negative) limit is designated as minimum, is used in this data sheet for logic levels only, e.g., when -5 V is the maximum, the typical value is a more negative voltage.

switching characteristics, $V_{CC+} = 12$ V, $V_{CC-} = -12$ V, $T_A = 25^\circ$ C (see Figure 1)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{TLH}	Transition time, low-to-high-level output	$C_L = 2500$ pF, $R_L = 3$ k Ω to 7 k Ω	0.2	1.4	2	μ s
t_{THL}	Transition time, high-to-low-level output		0.2	1.5	2	μ s
t_{TLH}	Transition time, low-to-high-level output	$C_L = 15$ pF, $R_L = 7$ k Ω		40		ns
t_{THL}	Transition time, high-to-low-level output			20		ns
t_{PLH}	Propagation delay time, low-to-high-level output	$C_L = 15$ pF, $R_L = 7$ k Ω		60		ns
t_{PHL}	Propagation delay time, high-to-low-level output			45		ns



PARAMETER MEASUREMENT INFORMATION



- NOTES: A. The pulse generator has the following characteristics: duty cycle $\leq 50\%$, $Z_O \approx 50 \Omega$.
B. C_L includes probe and jig capacitance.

Figure 1. Test Circuit and Voltage Waveforms

TYPICAL CHARACTERISTICS

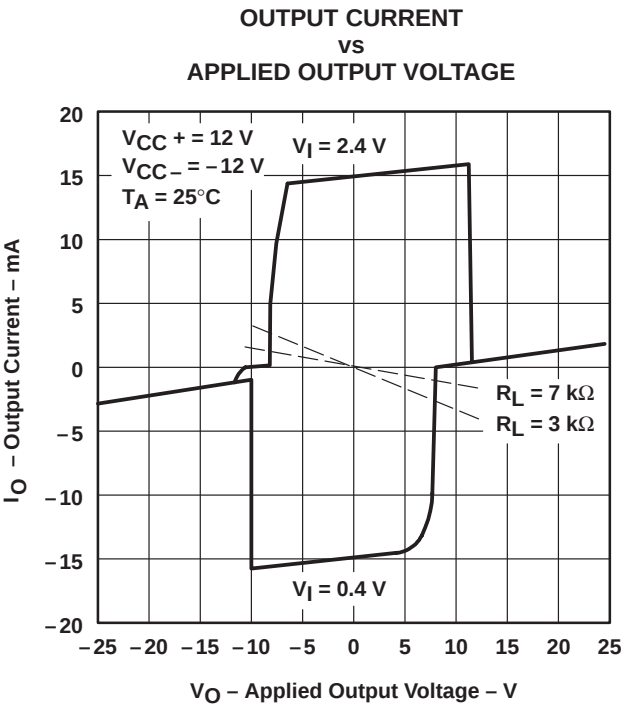


Figure 2

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN75150D	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	0 to 70	75150	Samples
SN75150DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	0 to 70	75150	Samples
SN75150DR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	NIPDAU	Level-1-260C-UNLIM	0 to 70	75150	Samples
SN75150P	ACTIVE	PDIP	P	8	50	Green (RoHS & no Sb/Br)	NIPDAU	N / A for Pkg Type	0 to 70	SN75150P	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "-" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

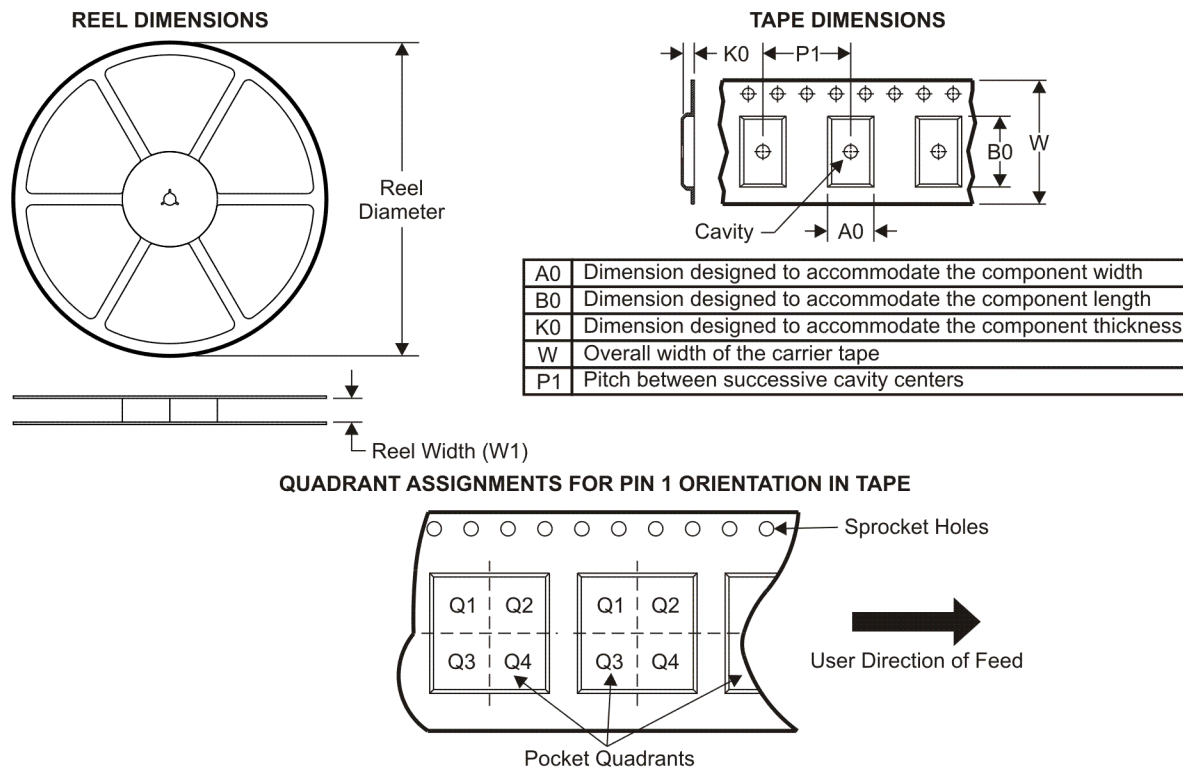
(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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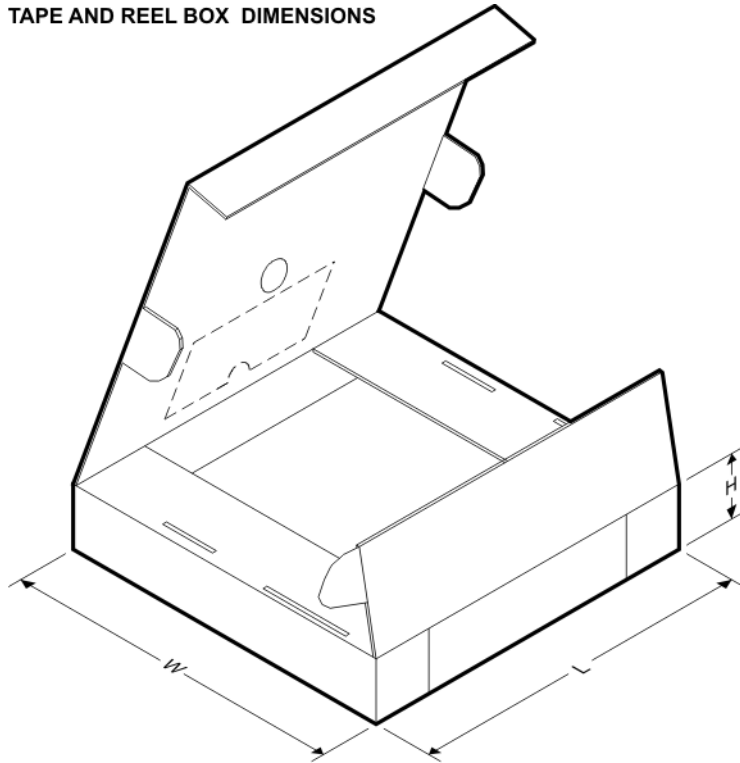
TAPE AND REEL INFORMATION



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75150DR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS

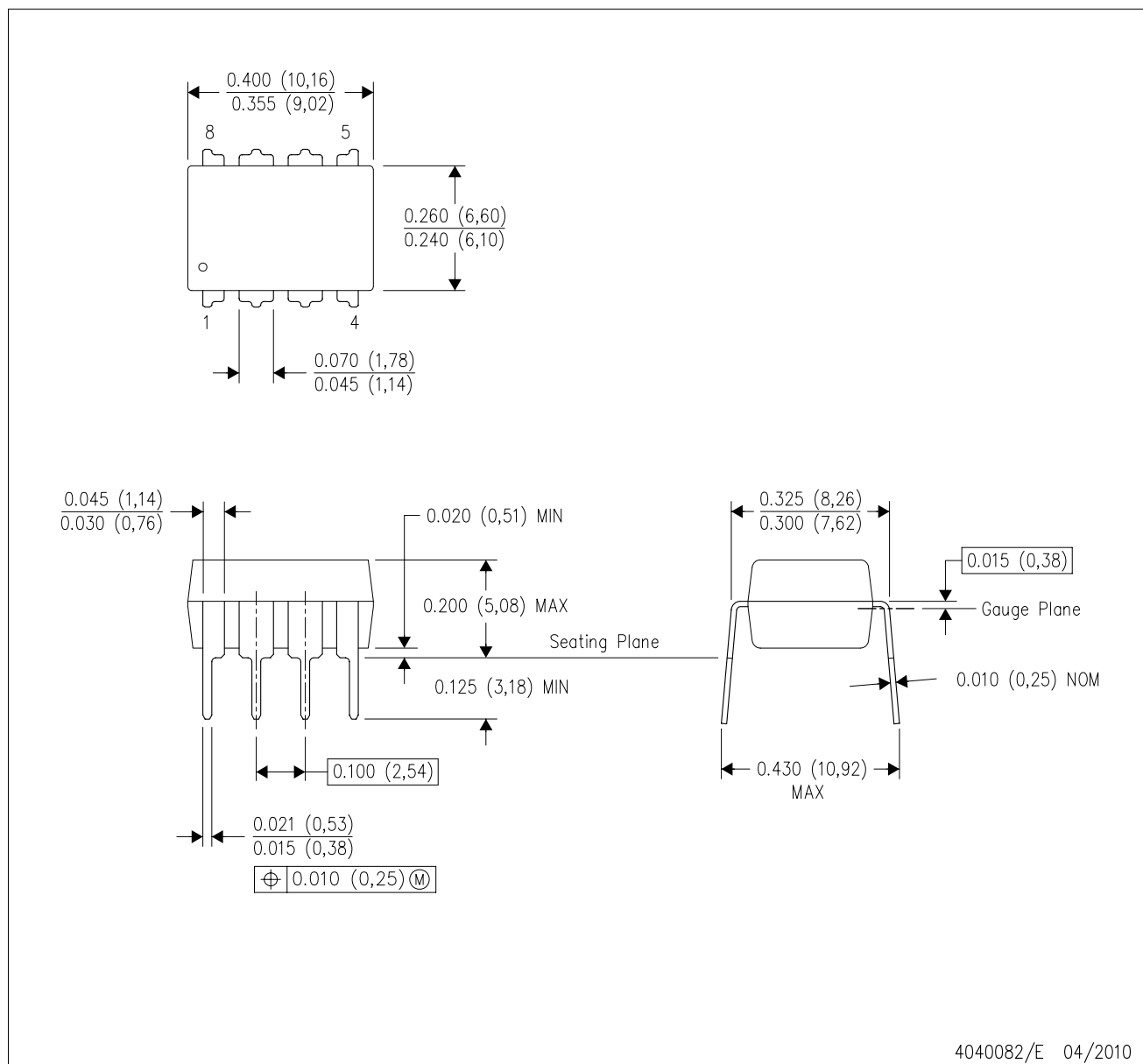


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75150DR	SOIC	D	8	2500	340.5	338.1	20.6

P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MS-001 variation BA.



PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT

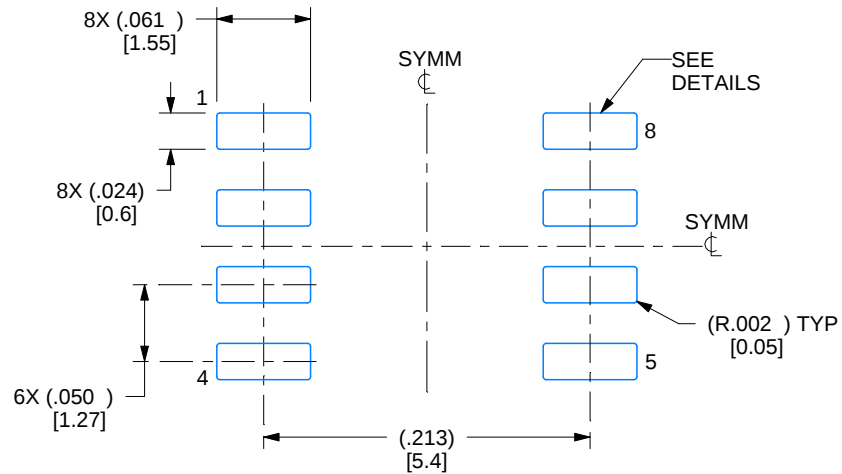


1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

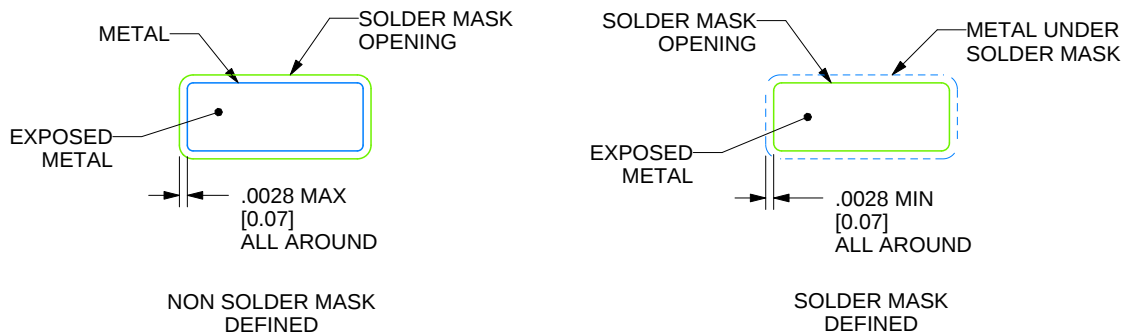
D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

4214825/C 02/2019

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

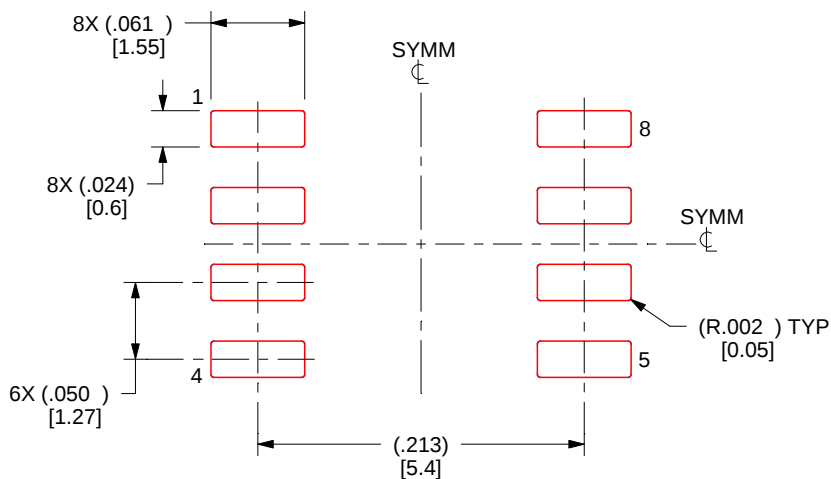
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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